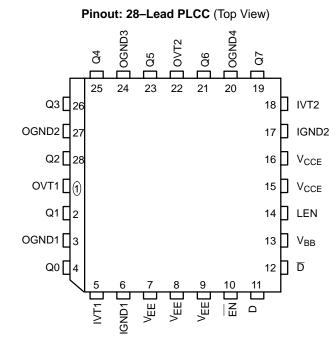
# Dual Supply ECL to TTL 1:8 Clock Driver

The MC10H/100H643 is a dual supply, low skew translating 1:8 clock driver. Devices in the Motorola H600 translator series utilize the 28–lead PLCC for optimal power pinning, signal flow through and electrical performance. The dual–supply H643 is similar to the H641, which is a single–supply 1:9 version of the same function.

The device features a 48mA TTL output stage, with AC performance specified into a 50pF load capacitance. A Latch is provided on-chip. When LEN is LOW (or left open, in which case it is pulled LOW by the internal pulldowns) the latch is transparent. A HIGH on the enable pin  $(\overline{EN})$  forces all outputs LOW.

The 10H version is compatible with MECL 10H<sup>™</sup> ECL logic levels. The 100H version is compatible with 100K levels.

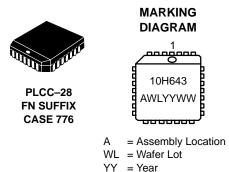
- ECL/TTL Version of Popular ECLinPS™ E111
- Low Skew Within Device 0.5ns
- Guaranteed Skew Spec Part-to-Part 1.0ns
- Latch
- Differential Internal Design
- V<sub>BB</sub> Output
- Dual Supply
- Reset/Enable
- Multiple TTL and ECL Power/Ground Pins





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#### WW = Work Week

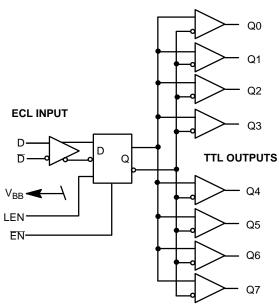
#### **PIN NAMES**

PIN	FUNCTION
OGND	TTL Output Ground (0V)
OVT	TTL Output V <sub>CC</sub> (+5.0V)
IGND	Internal TTL GND (0V)
IVT	Internal TTL V <sub>CC</sub> (+5.0V)
V <sub>EE</sub>	ECL V <sub>EE</sub> (-5.2/-4.5V)
V <sub>CCE</sub>	ECL Ground (0V)
D, D	Signal Input (ECL)
V <sub>BB</sub>	V <sub>BB</sub> Reference Output
Q0–Q7	Signal Outputs (TTL)
EN	Enable Input (ECL)
LEN	Latch Enable Input (ECL)

#### **ORDERING INFORMATION**

Device	Package	Shipping
MC10H643FN	PLCC-28	37 Units/Rail
MC100H643FN	PLCC-28	37 Units/Rail

#### LOGIC DIAGRAM



**DC CHARACTERISTICS** (IVT = OVT = 5.0V  $\pm$ 5%; V<sub>EE</sub> = -5.2V  $\pm$ 5% (10H Version); V<sub>EE</sub> = -4.2V to -5.5V (100H Version))

			0°C		25°C		85°C			
Symbol	Characteristic	;	Min	Мах	Min	Max	Min	Max	Unit	Condition
I <sub>EE</sub>		ECL	-	42	-	42	-	42	mA	V <sub>EE</sub> Pins
I <sub>CCL</sub>	Power Supply Current	TTL	-	106	I	106	-	106	mA	Total all OVT
I <sub>CCH</sub>			-	95	-	95	-	95	mA	and IVT pins

		0°C		25	°C	85°C			
Symbol	Characteristic	Min	Max	Min	Max	Min	Мах	Unit	Condition
t <sub>PLH</sub>	Propagation Delay to Output D LEN EN	4.0 3.5 3.5	5.0 5.5 5.5	4.1 3.5 3.5	5.1 5.5 5.5	4.4 3.9 3.9	5.4 5.9 5.9	ns	CL = 50pF
t <sub>SKEW</sub>	Within–Device Skew	-	0.5	-	0.5		0.5	ns	Note 1
tw	Pulse Width Out HIGH or LOW @ f <sub>out</sub> = 50MHz	9.0	11.0	9.0	11.0	9.0	11.0	ns	CL = 50pF Note 2
t <sub>s</sub>	Setup Time D	0.75	_	0.75	-	0.75	-	ns	
t <sub>h</sub>	Hold Time D	0.75	_	0.75	-	0.75	-	ns	
t <sub>RR</sub>	Recovery Time LEN EN	1.25 1.25		1.25 1.25		1.25 1.25	-	ns	
t <sub>pw</sub>	Minimum Pulse Width LEN EN	1.5 1.5	-	1.5 1.5	-	1.5 1.5	-	ns	
t <sub>r</sub> t <sub>f</sub>	Rise / Fall Times 0.8 V – 2.0 V	-	1.2	-	1.2	-	1.2	ns	CL = 50pF

Within–Device skew defined as identical transitions on similar paths through a device.
Pulse width is defined relative to 1.5V measurement points on the output waveform.

#### TRUTH TABLE

D	LEN	EN	Q
L H X X	L L H X	L L H	L H QO L

#### DC TTL CHARACTERISTICS

(IVT = OVT = 5.0V  $\pm$ 5%; V<sub>EE</sub> = -5.2V  $\pm$ 5% (10H Version); V<sub>EE</sub> = -4.2 V to -5.5 V (100H Version))

		0°C		25°C		85°C			
Symbol	Characteristic	Min	Max	Min	Мах	Min	Max	Unit	Condition
V <sub>OH</sub>	Output HIGH Voltage	2.5 2.0		2.5 2.0	-	2.5 2.0	-	V	I <sub>OH</sub> = -3.0mA I <sub>OH</sub> = -15mA
V <sub>OL</sub>	Output LOW Voltage	-	0.5	-	0.5	-	0.5	V	I <sub>OH</sub> = 48mA
IOS	Output Short Circuit Current	-100	-225	-100	-225	-100	-225	mA	$V_{OUT} = 0V$

#### **10H ECL DC CHARACTERISTICS**

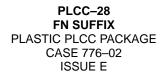
(IVT = OVT = 5.0V  $\pm$ 5%; V<sub>EE</sub> = -5.2V  $\pm$ 5% (10H Version))

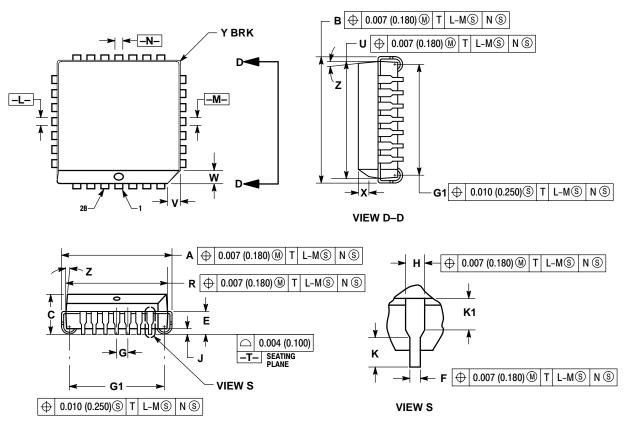
		0°C		25°C		85°C			
Symbol	Characteristic	Min	Мах	Min	Мах	Min	Max	Unit	Condition
I <sub>INH</sub> I <sub>INL</sub>	Input HIGH Current Input LOW Current	_ 0.5	225 -	_ 0.5	175 -	_ 0.5	175 -	μΑ	
V <sub>IH</sub> V <sub>IL</sub>	Input HIGH Voltage Input LOW Voltage	-1170 -1950	-840 -1480	-1130 -1950	-810 -1480	-1070 -1950	-735 -1450	mV	
V <sub>BB</sub>	Output Reference Voltage	-1380	-1270	-1350	-1250	-1310	-1190	mV	

#### 100H ECL DC CHARACTERISTICS (IVT = OVT = 5.0V $\pm$ 5%; V<sub>EE</sub> = -4.2 V to -5.5 V (100H))

		0°C		25°C		85°C			
Symbol	Characteristic	Min	Мах	Min	Мах	Min	Мах	Unit	Condition
I <sub>INH</sub> I <sub>INL</sub>	Input HIGH Current Input LOW Current	_ 0.5	225 -	_ 0.5	175 -	_ 0.5	175 -	μΑ	
V <sub>IH</sub> V <sub>IL</sub>	Input HIGH Voltage Input LOW Voltage	-1165 -1810	880 1475	-1165 -1810	880 1475	-1165 -1810	880 1475	mV	
V <sub>BB</sub>	Output Reference Voltage	-1380	-1260	-1380	-1260	-1380	-1260	mV	

#### PACKAGE DIMENSIONS





NOTES:

- 1. DATUMS -L-, -M-, AND -N- DETERMINED WHERE TOP OF LEAD SHOULDER EXITS PLASTIC BODY AT MOLD PARTING LINE.
- DIMENSION G1, TRUE POSITION TO BE MEASURED AT DATUM -T-, SEATING PLANE.
  DIMENSIONS R AND U DO NOT INCLUDE MOLD FLASH, ALLOWABLE MOLD FLASH IS
- MOLD FLASH. ALLOWABLE MOLD FLASH IS 0.010 (0.250) PER SIDE. 4. DIMENSIONING AND TOLERANCING PER
- DIMENSIONING AND TOLERANCING ANSI Y14.5M, 1982.
  CONTROLLING DIMENSION: INCH.
- 5. CON INDULING DIMENSION: INCH. 6. THE PACKAGE TOP MAY BE SMALLER THAN THE PACKAGE BOTTOM BY UP TO 0.012 (0.300). DIMENSIONS R AND U ARE DETERNINED AT THE OUTERMOST EXTREMES OF THE PLASTIC BODY EXCLUSIVE OF MOLD FLASH, TIE BAR BURRS, GATE BURRS AND INTERLEAD FLASH, BUT INCLUDING ANY MISMATCH BETWEEN THE TOP AND BOTTOM OF THE PLASTIC RODY
- MILLIMETERS INCHES DIM MIN MAX MIN MAX 12.32 A 0.485 0.495 12.57 **B** 0.485 0.495 12.32 12.57 C 0.165 0.180 4.20 4.57 E 0.090 0.110 F 0.013 0.019 2.29 2.79 0.33 0.48 G 0.050 BSC 1.27 BSC Η 0.026 0.032 0.66 0.81 J 0.020 K 0.025 0.51 0.64 R 0.450 0.456 11.43 11.58 U 0.450 V 0.042 0.456 11.43 11.58 0.048 1.07 1.21 W 0.042 0.048 1.07 1.21 X 0.042 0.056 1.07 1.42 Y 0.020 0.50 2 ( 2 z 10° 10° G1 0.410 0.430 10.42 10.92 K1 0.040 1.02
- PLASTIC BODY. 7. DIMENSION H DOES NOT INCLUDE DAMBAR PROTRUSION OR INTRUSION. THE DAMBAR PROTRUSION(S) SHALL NOT CAUSE THE H DIMENSION TO BE GREATER THAN 0.037 (0.940). THE DAMBAR INTRUSION(S) SHALL NOT CAUSE THE H DIMENSION TO BE SMALLER THAN 0.025 (0.635).

## <u>Notes</u>

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